Sensors

Photointerrupter, double-layer mold type RPI-243

The RPI-243 is a compact, double-layer mold photointerrupter.

Applications
Floppy disk drives
Printers
CD-ROM

Features

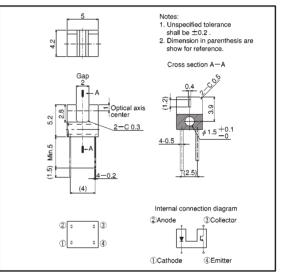
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Operating temperature

Storage temperature

- 1) Compact package based on the double-mold method.
- 2) High resolution (slit width = 0.4 mm).
- 3) Gap between emitter and detector is 2.0 mm.





Absolute maximum ratings (ra = 25°C)							
Parameter		Symbol	Limits	Unit			
Input(LED)	Forward current	lF	50	mA			
	Reverse voltage	VR	5	V			
	Power dissipation	PD	80	mW			
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V			
	Emitter-collector voltage	Veco	4.5	V			
	Collector current	lc	30	mA			
	Collector power dissipation	Pc	80	mW			

Topr

Tstg

• Absolute maximum ratings (Ta = 25° C)

 $-25 \sim +85$

 $-30 \sim +100$

°C

°C

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage	VF	—	1.3	1.6	V	I⊧=50mA
	Reverse current	le le	_	—	10	μA	V _R =5V
Output charac- teristics	Dark current	ICEO	_	_	0.5	μA	V _{CE} =10V
	Peak sensitivity wavelength	λp	_	800	_	nm	—
Transfer charac- teristics	Collector current	lc	0.5	_	_	mA	VcE=5V, I⊧=20mA
	Collector-emitter saturation voltage	VCE(sat)	_	_	0.4	v	I⊧=20mA, Ic=0.3mA
	Response time	tr∙tf	_	10	_	μs	Vcc=5V, I⊧=20mA, RL=100Ω

•Electrical and optical characteristics (Ta = 25° C)

Electrical and optical characteristic curves

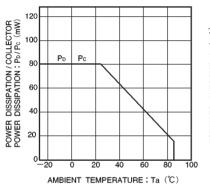


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

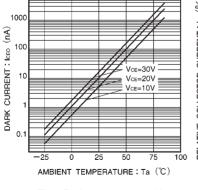


Fig.4 Dark current vs. ambient temperature

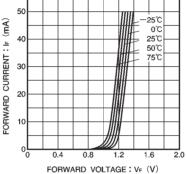
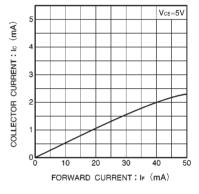
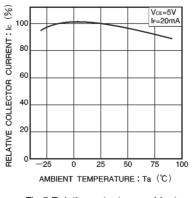
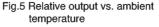


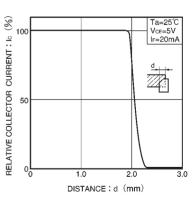
Fig.2 Forward current vs. forward voltage



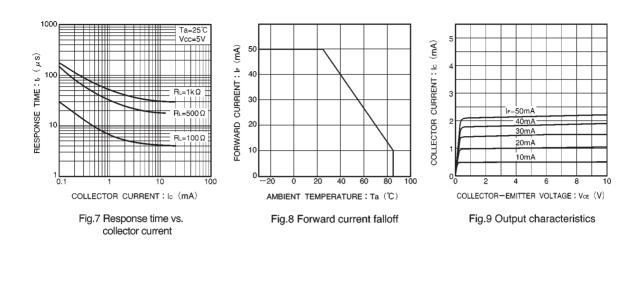


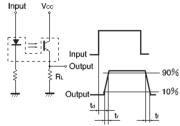












- t₀ : Delay time
- tr : Rise time (time for output current to rise from 10% to 90% of peak current)
- tr : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.10 Response time measurement circuit

